TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7MBL3245SFT, TC7MBL3245SFK, TC7MBL3245SFTG

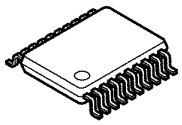
Low Voltage/Low Capacitance Octal Bus Switch

The TC7MBL3245S provides eight bits of low- voltage, high-speed bus switching in a standard '245 device pinout. The low ON-resistance of the switch allows connections to be made with minimal propagation delay and while maintaining CMOS low power dissipation.

The device comprises a single 8-bit switch. When output enable ($\overline{OE}$) is low, the switch is on and port A is connected to port B. When $\overline{OE}$ is high, the switch is open and a high-impedance state exists between the two ports.

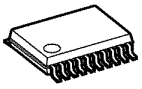
All inputs are equipped with protection circuits to guard against static discharge.

TC7MBL3245SFT



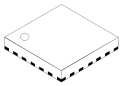
TSSOP20-P-0044-0.65A

TC7MBL3245SFK



VSSOP20-P-0030-0.50

TC7MBL3245CFTG



VQON20-P-0404-0.50

Features

- Operating voltage: V_{CC} = 1.65 to 3.6 V
- Low capacitance: $C_{I/O}$ = 12 pF Switch On (typ.) @3 V
- Low on resistance: R_{ON} = 9 Ω (typ.) @3 V
- ESD performance: Machine model ≥ ±200 V
  Human body model ≥ ±2000 V
- Power down protection for inputs ($\overline{OE}$ input only)
- Package: TSSOP20,VSSOP (US20) , VQON20
- Pin compatible with the 74xx245 type

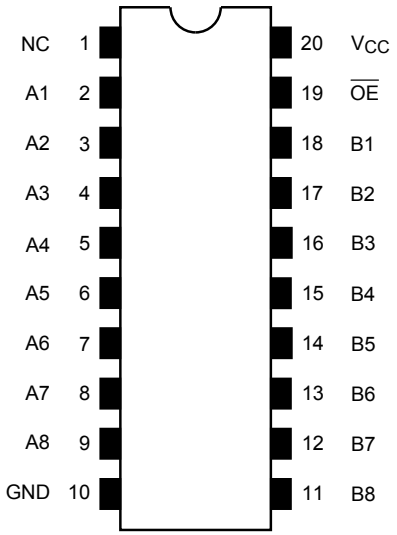
Note: When mounting VQON package, the type of recommended flux is RA or RMA.

Weight

TSSOP20-P-0044-0.65A	: 0.08 g (typ.)
VSSOP20-P-0030-0.50	: 0.03 g (typ.)
VQON20-P-0404-0.50	: 0.0145g (typ.)

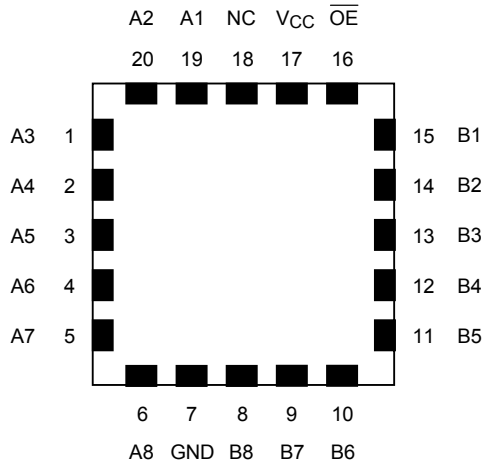
Pin Assignment (top view)

FT (TSSOP20-P-0044-0.65A)
FK (VSSOP20-P-0030-0.50)



NC-No Internal Connection

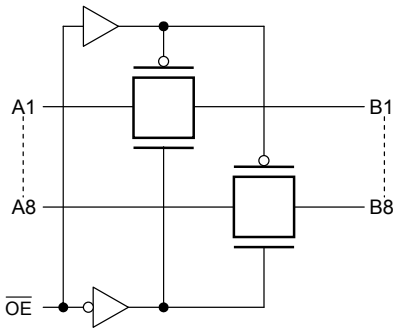
FTG (VQON20-P-0404-0.50)



Truth Table

Inputs $\overline{OE}$	Function
L	A port = B port
H	Disconnect

System Diagram



Absolute Maximum Ratings (Note)

Characteristic		Symbol	Rating	Unit
Power supply voltage		V_{CC}	−0.5 to 4.6	V
Control pin input voltage		V_{IN}	−0.5 to 4.6	V
Switch terminal I/O voltage		V_S	−0.5 to V_{CC} + 0.5	V
Clump diode current	Control input pin	I_{IK}	−50	mA
	Switch terminal		±50	mA
Switch I/O current		I_S	50	mA
Power dissipation		P_D	180	mW
DC V_{CC}/GND current		I_{CC}/I_{GND}	±100	mA
Storage temperature		T_{stg}	−65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Operating Ranges (Note)

Characteristic	Symbol	Rating	Unit
Power supply voltage	V_{CC}	1.65 to 3.6	V
Control pin input voltage	V_{IN}	0 to 3.6	V
Switch I/O voltage	V_S	0 to V_{CC}	V
Operating temperature	T_{opr}	−40 to 85	°C
Input rise and fall time	dt/dv	0 to 10	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Electrical Characteristics

DC Characteristics (Ta = –40 to 85°C)

Parameter		Symbol	Test Condition	V_{CC} (V)	Min	Typ.	Max	Unit
Input voltage	"H" level	V_{IH}	—	1.65 to 3.6	0.7 × V_{CC}	—	—	V
	"L" level	V_{IL}	—	1.65 to 3.6	—	—	0.3 × V_{CC}	
Input leakage current		I_{IN}	V_{IN} = 0 to 3.6V	1.65 to 3.6	—	—	±1.0	μA
Power off leakage current		I_{OFF}	$\overline{OE}$ = 0 to 3.6 V	0	—	—	1.0	μA
Off-state leakage current (switch off)		I_{SZ}	A, B = 0 to V_{CC} , $\overline{OE}$ = V_{CC}	1.65 to 3.6	—	—	±1.0	μA
On resistance (Note2)		R_{ON}	V_{IS} = 0 V, I_{IS} = 30 mA (Note1)	3.0	—	9	13	Ω
			V_{IS} = 3.0 V, I_{IS} = 30 mA (Note1)	3.0	—	15	20	
			V_{IS} = 2.4 V, I_{IS} = 15 mA (Note1)	3.0	—	19	27	
			V_{IS} = 0 V, I_{IS} = 24 mA (Note1)	2.3	—	10	16	
			V_{IS} = 2.3 V, I_{IS} = 24 mA (Note1)	2.3	—	17	24	
			V_{IS} = 2.0 V, I_{IS} = 15 mA (Note1)	2.3	—	21	30	
Quiescent supply current		I_{CC}	V_{IN} = V_{CC} or GND, I_{OUT} = 0	3.6	—	—	10	μA

Note1: All typical values are at Ta=25°C.

Note2: Measured by the voltage drop between A and B pins at the indicated current through the switch. On resistance is determined by the lower of the voltages on the two (A or B) pins.

AC Characteristics (Ta = –40 to 85°C)

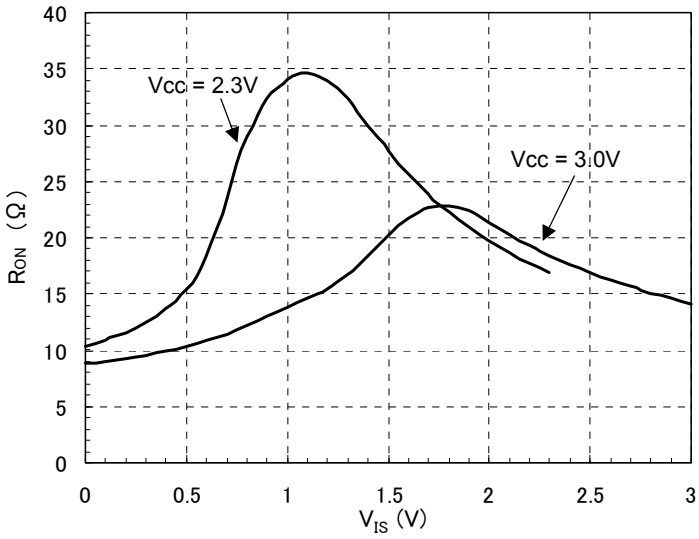
Characteristics	Symbol	Test Condition	V_{CC} (V)	Min	Max	Unit
Output enable time	t_{pZL} t_{pZH}	Figure 1, Figure 2	3.3 ± 0.3	—	6	ns
			2.5 ± 0.2	—	7	
			1.8 ± 0.15	—	11	
Output disable time	t_{pLZ} t_{pHZ}	Figure 1, Figure 2	3.3 ± 0.3	—	6	ns
			2.5 ± 0.2	—	7	
			1.8 ± 0.15	—	11	

Capacitive Characteristics (Ta = 25°C)

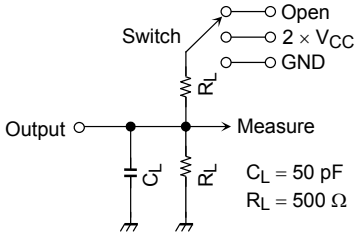
Characteristics (Note)	Symbol	Test Condition	V_{CC} (V)	Typ.	Unit
Control pin input capacitance	C_{IN}		3.0	3	pF
Switch terminal capacitance	$C_{I/O}$	$\overline{OE}$ = V_{CC} (switch off)	3.0	6	pF
		$\overline{OE}$ = GND (switch on)	3.0	12	pF

Note : This parameter is guaranteed by design

R_{ON} Characteristic (typ.) Ta=25℃



AC Test Circuit



Parameter	Switch
t_{pLH}, t_{pHL}	Open
t_{pLZ}, t_{pZL}	2 × V_{CC}
t_{pHZ}, t_{pZH}	GND

Figure 1

AC Waveform

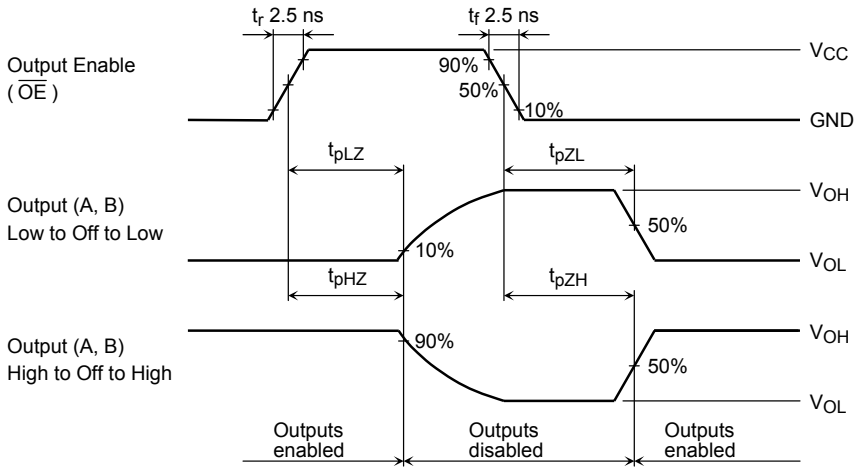


Figure 2 t_{pLZ}, t_{pHZ}, t_{pZL}, t_{pZH}

Rise and Fall Times (tr / tf) of the TC7MBL3245S I/O Signals

The tr(out) and tf(out) values of the output signals are affected by the CR time constant of the input, which consists of the switch terminal capacitance ($C_{I/O}$) and the on-resistance (R_{ON}) of the input.

In practice, the tr(out) and tf(out) values are also affected by the circuit's capacitance and resistance components other than those of the TC7MBL3245S.

The tr(out) / tf(out) values can be approximated as follows. (Figure 3 shows the test circuit.)

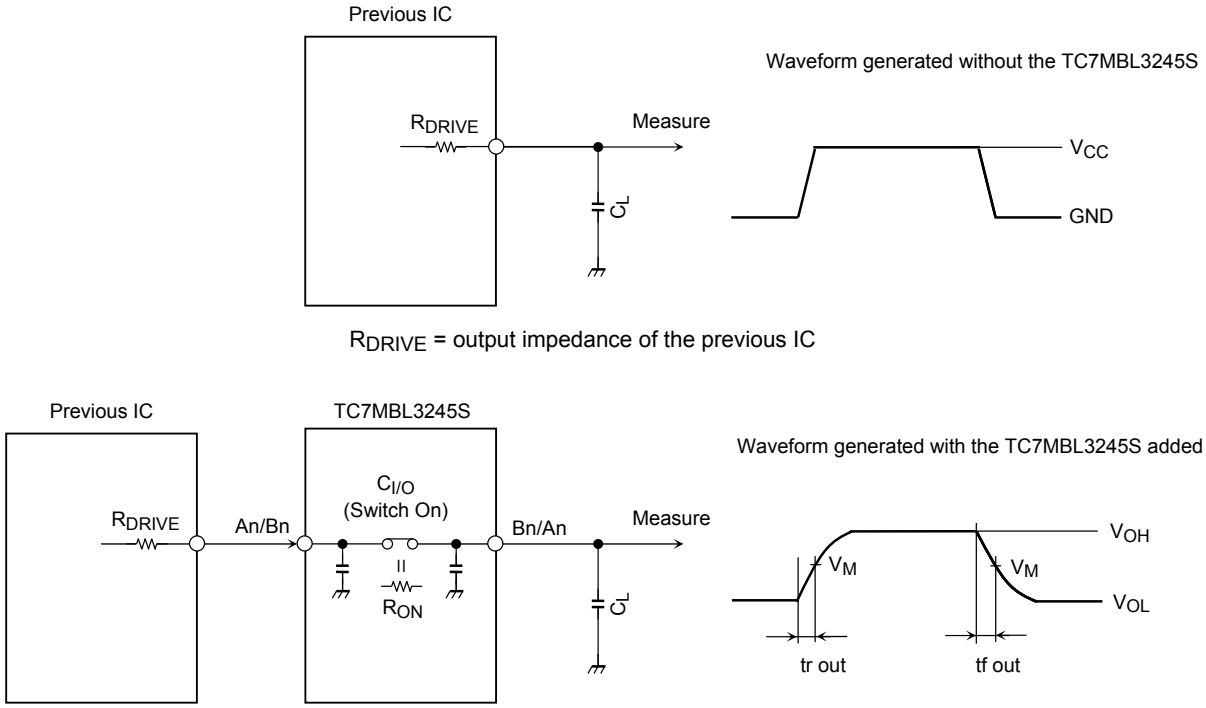
$$tr(out) / tf(out) (approx) = - (C_{I/O} + C_L) \cdot (R_{DRIVE} + R_{ON}) \cdot \ln (((V_{OH} - V_{OL}) - V_M) / (V_{OH} - V_{OL}))$$

where, R_{DRIVE} is the output impedance of the previous-stage circuit.

Calculation example:

$$tr(out) (approx) = - (12 + 15)E-12 \cdot (120 + 9) \cdot \ln (((3.0 - 0) - 1.5) / (3.0 - 0))$$
$$\approx 2.4ns$$

Calculation conditions:
V_{CC} = 3.0V , C_L = 15pF , R_{DRIVE} = 120 Ω (output impedance of the previous IC), V_M = 1.5V(V_{CC} / 2)
Output of the previous IC = digital (i.e., high-level voltage = V_{CC}; low-level voltage = GND)

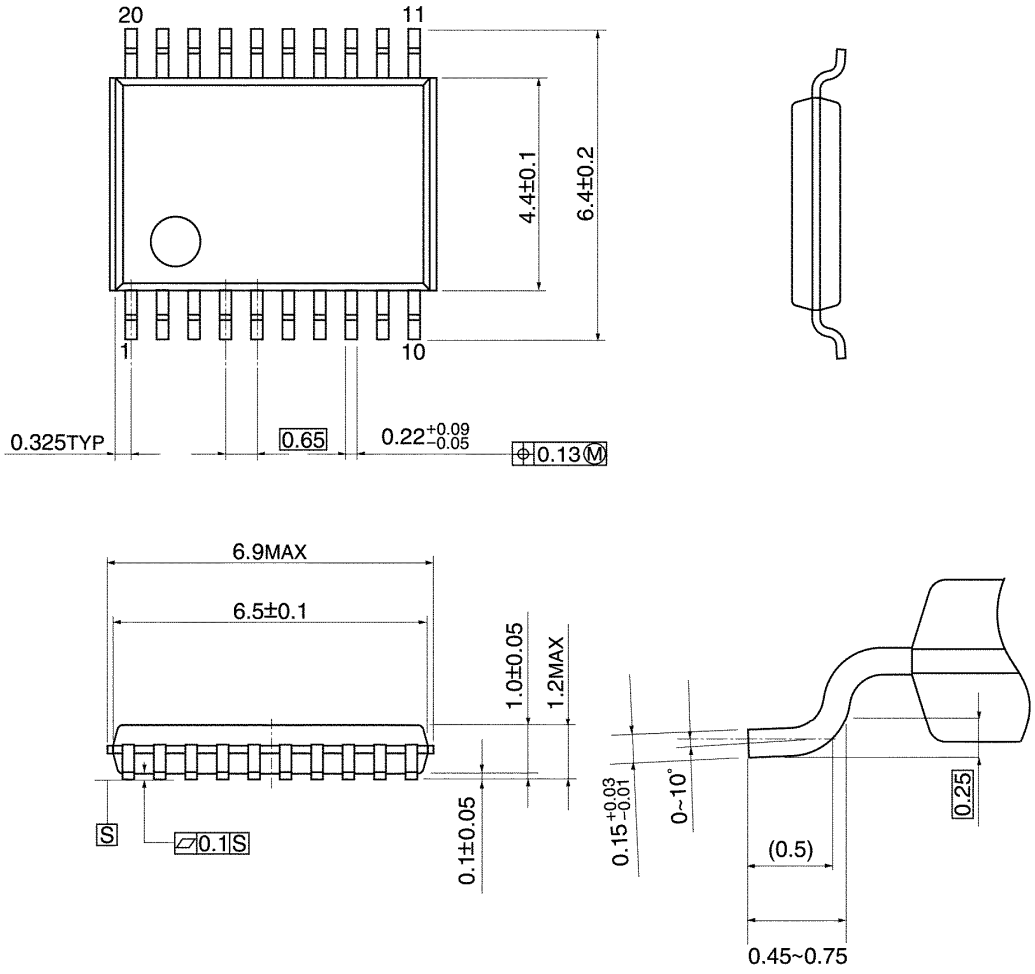


Parameter	V_{CC}		
	3.3 ± 0.3 V	2.5 ± 0.2 V	1.8 ± 0.15 V
V_M	V_{CC} / 2	V_{CC} / 2	V_{CC} / 2

Figure 3 Test Circuit

Package Dimensions

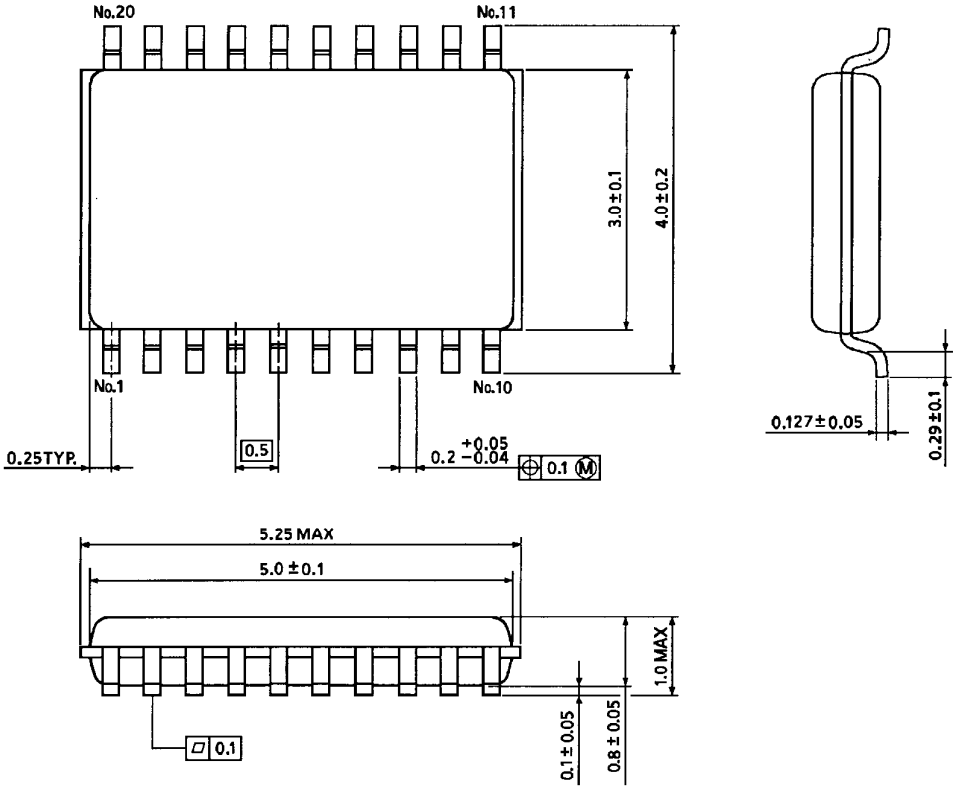
TSSOP20-P-0044-0.65A Unit: mm



Weight: 0.08g (typ.)

Package Dimensions

VSSOP20-P-0030-0.50 Unit : mm

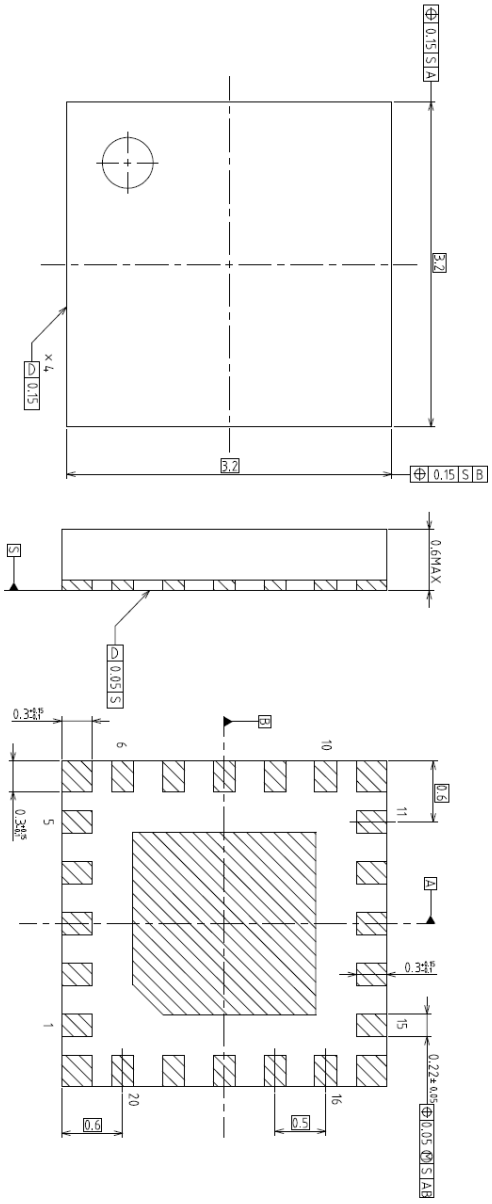


Weight: 0.03g (typ.)

Package Dimensions

VQON20-P-0404-0.50

Unit : mm



Weight: 0.0145 g (typ.)

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20070701-EN GENERAL

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